20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A. TELEPHONE: (973) 376-2922

(212) 227-6005

FAX: (973) 376-8960

# NPN - MPSA05, MPSA06\*; PNP - MPSA55, MPSA56\*

\*Preferred Devices

# **Amplifier Transistors**

Voltage and Current are Negative for PNP Transistors

#### **MAXIMUM RATINGS**

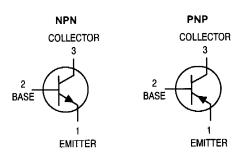
Rating	Symbol	Value	Unit
Collector - Emitter Voltage MPSA05, MPSA55 MPSA06, MPSA56	V <sub>ÇEO</sub>	60 80	Vdc
Collector - Base Voltage MPSA05, MPSA55 MPSA06, MPSA56	V <sub>CBO</sub>	60 80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	4.0	Vdc
Collector Current - Continuous	Ic	500	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

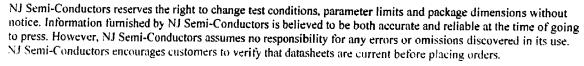
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 1)	R <sub>θJA</sub>	200	°CW
Thermal Resistance, Junction-to-Case	R <sub>0JC</sub>	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

R<sub>0JA</sub> is measured with the device soldered into a typical printed circuit board.





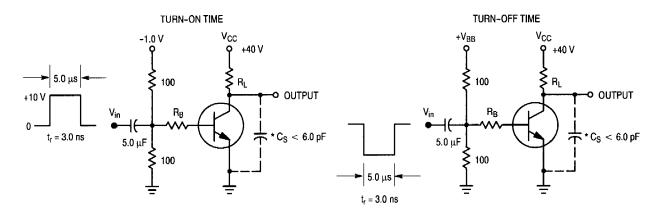


### NPN - MPSA05, MPSA06\*; PNP - MPSA55, MPSA56\*

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 2) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	MPSA05, MPSA55 MPSA06, MPSA56	V <sub>(BR)CEO</sub>	60 80	-	Vdc
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 100 µAdc, I <sub>C</sub> = 0)		V <sub>(BR)EBO</sub>	4.0	-	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, I <sub>B</sub> = 0)		Ices	-	0.1	μAdc
Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$	MPSA05, MPSA55 MPSA06, MPSA56	Ісво	<u>-</u>	0.1 0.1	μAdc
ON CHARACTERISTICS					
DC Current Gain ( $I_C$ = 10 mAdc, $V_{CE}$ = 1.0 Vdc) ( $I_C$ = 100 mAdc, $V_{CE}$ = 1.0 Vdc)		h <sub>FE</sub>	100 100		-
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)		V <sub>CE(sat)</sub>	-	0.25	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 1.0 Vdc)		V <sub>BE(on)</sub>	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (Note 3) (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 2.0 V, f = 100 MHz)	MPSA05 MPSA06	f <sub>T</sub>	100	_	MHz
$(I_C = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}, f = 100 \text{ MHz})$	MPSA55 MPSA56		50	_	

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.



\*Total Shunt Capacitance of Test Jig and Connectors For PNP Test Circuits, Reverse All Voltage Polarities

Figure 1. Switching Time Test Circuits